

## Subject card

Subject name and code	Integrated Active Circuits for Wireless Communications, PG_00048662								
Field of study	Electronics and Telecommunications								
Date of commencement of studies	February 2023		Academic year of realisation of subject			2022/2023			
Education level	second-cycle studies		Subject group			Optional subject group Subject group related to scientific research in the field of study			
Mode of study	Full-time studies		Mode of delivery			at the university			
Year of study	1		Language of instruction			Polish			
Semester of study	1		ECTS credits			3.0			
Learning profile	general academic profile		Assessment form			assessment			
Conducting unit	Department of Microwave and Antenna Engineering -> Faculty of Electronics, Telecommunications and Informatics								
Name and surname of lecturer (lecturers)	Subject supervisor		dr hab. inż. Krzysztof Nyka						
	Teachers	dr hab. inż. Krzysztof Nyka							
Lesson types and methods of instruction	Lesson type	Lecture	Tutorial	Laboratory	ooratory Project		Seminar	SUM	
	Number of study hours	15.0	0.0	30.0	0.0		0.0	45	
	E-learning hours included: 0.0								
Learning activity and number of study hours	Learning activity	Participation in didactic classes included in study plan		Participation in consultation hours		Self-study		SUM	
	Number of study hours	45		6.0		24.0		75	
Subject objectives	Theoretical knowledge about concepts, operation, analysis, measurements and basic design procedures of the RF and microwave active circuits for wireless communication systems. Theoretical knowledge about designing RF active circuits using planar microwave circuit technologies and about using monolithic integrated circuits. Practical skills in analysis and basic design of RF active circuits in advanced CAD simulation software.								
Learning outcomes	Course outcome		Subject outcome			Method of verification			
	[K7_W03] Knows and understands, to an increased extent, the construction and operating principles of components and systems related to the field of study, including theories, methods and complex relationships between them and selected specific issues - appropriate for the curriculum.		Student knows properties of operation, methods of simulation, measurements and fabrication of RF active circuits for wireless communication			[SW1] Assessment of factual knowledge			
	[K7_W06] Knows and understands, to an increased extent, the basic processes taking place in the life cycle of devices, facilities and technical systems.		Students knows problems concerning fsabrication of RF active circuits in available technologies			[SW1] Assessment of factual knowledge			
	K7_K02		Student applies theoretical knowlegde from the lectrues for solving practical problems during the design of RF active circuits			[SK2] Assessment of progress of work			
	[K7_U06] can analyse the operation of components, circuits and systems related to the field of study; measure their parameters; examine technical specifications; interpret obtained results and draw conclusions		Student determines parameters of active circuits and their influence on operation and performance of wireless communication system. Students interprets design requirements and designs active RF circuits.			[SU4] Assessment of ability to use methods and tools [SU1] Assessment of task fulfilment			

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Subject contents	Lecture						
	<ul> <li>Introduction to active RF circuits and review of RF integrated circuit technologies</li> <li>RF transistor amplifiers – classification, parameters; biasing of the RF transistors</li> <li>Small signal amplifier design – conjugate match, definitions of gain, constant gain circles</li> <li>Lumped and distributed matching networks</li> <li>Small signal amplifier design – stability</li> <li>Low noise amplifier – noise matching, constant noise figure circuits</li> <li>Broadband RF amplifiers</li> <li>Nonlinear distortions and other nonlinear effects in RF circuits, the methods of large signal simulation in ADS</li> <li>RF transistors power amplifiers – class A, AB</li> <li>RF transistors power amplifiers – techniques of linearization and efficiency improvement</li> <li>RF transistors oscillators – introduction to feedback and negative resistance oscillators</li> <li>Laboratory</li> <li>Small signal simulation of RF transistors in ADS, introduction to ADS</li> <li>Design and investigation of narrowband RF transistor small signal amplifiers</li> <li>Broadband and selective stabilization of RF transistor amplifiers</li> <li>Large signal simulation in ADS (HB, Transient) – introduction</li> <li>Investigation of nonlinear effects in RF amplifiers</li> </ul>						
Prerequisites and co-requisites	Basic knowledge of the RF active circuits characterization and principles of RF amplifier design. Recommended prior course: Wireless Circuit Design						
Assessment methods and criteria	Subject passing criteria	Passing threshold	Percentage of the final grade				
	Laboratory - presence and reports	50.0%	40.0%				
	Lecture - final test	50.0%	50.0%				
	Lecture - presence	0.0%	10.0%				
Recommended reading	Basic literature	D. Pozar, Microwave Engineering John Wley&Sons 1998     Advanced Design System 2012.08 Documentation Set					
	Supplementary literature	F. Ellinger, Radio Frequency Ir Springer-Verlag, 2007	ntegrated Circuits and Technologies,				
	eResources addresses						
Example issues/ example questions/ tasks being completed	Compare different types of impedance matching in RF amplifiers.  Present properties of operation of RF transistor biasing networks						
Work placement	Not applicable						

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